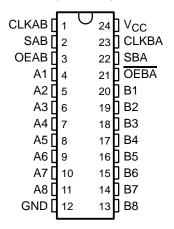
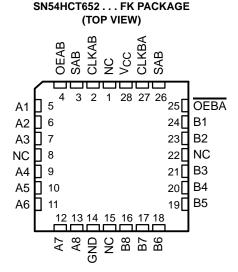
- Operating Voltage Range of 4.5 V to 5.5 V
- Low Power Consumption, 80-μA Max I<sub>CC</sub>
- Typical t<sub>pd</sub> = 12 ns
- ±6-mA Output Drive at 5 V
- Low Input Current of 1 μA Max
- Inputs Are TTL-Voltage Compatible

SN54HCT652...JT OR W PACKAGE SN74HCT652...DW OR NT PACKAGE (TOP VIEW)



- Independent Registers and Enables for A and B Buses
- Multiplexed Real-Time and Stored Data
- True Data Paths
- High-Current 3-State Outputs Can Drive Up To 15 LSTTL Loads



NC - No internal connection

## description/ordering information

The 'HCT652 devices consist of bus-transceiver circuits, D-type flip-flops, and control circuitry arranged for multiplexed transmission of data directly from the data bus or from the internal storage registers. Output-enable (OEAB and  $\overline{OEBA}$ ) inputs are provided to control the transceiver functions. Select-control (SAB and SBA) inputs are provided to select real-time or stored data transfer. A low input level selects real-time data; a high input level selects stored data. Figure 1 illustrates the four fundamental bus-management functions that can be performed with these devices.

#### ORDERING INFORMATION

TA	PACKAGE <sup>†</sup>		ORDERABLE PART NUMBER	TOP-SIDE Marking
	PDIP – NT Tube		SN74HCT652NT	SN74HCT652NT
-40°C to 85°C	SOIC - DW	Tube	SN74HCT652DW	HCT652
	30IC - DW	Tape and reel	SN74HCT652DWR	HC1032
	CDIP – JT	Tube	SNJ54HCT652JT	SNJ54HCT652JT
–55°C to 125°C	CFP – W	Tube	SNJ54HCT652W	SNJ54HCT652W
	LCCC – FK	Tube	SNJ54HCT652FK	SNJ54HCT652FK

<sup>†</sup> Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



## SN54HCT652, SN74HCT652 **OCTAL BUS TRANSCEIVERS AND REGISTERS** WITH 3-STATE OUTPUTS

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## description/ordering information (continued)

Data on the A or B data bus, or both, can be stored in the internal D-type flip-flops by low-to-high transitions at the appropriate clock (CLKAB or CLKBA) terminals, regardless of the select- or output-control terminals. When SAB and SBA are in the real-time transfer mode, it is possible to store data without using the internal D-type flip-flops by simultaneously enabling OEAB and OEBA. In this configuration, each output reinforces its input. When all other data sources to the two sets of bus lines are at high impedance, each set of bus lines remains at its last state.

To ensure the high-impedance state during power up or power down, OEBA should be tied to V<sub>CC</sub> through a pullup resistor and OEAB should be tied to GND through a pulldown resistor; the minimum value of the resistor is determined by the current-sinking/current-sourcing capability of the driver.

#### **FUNCTION TABLE**

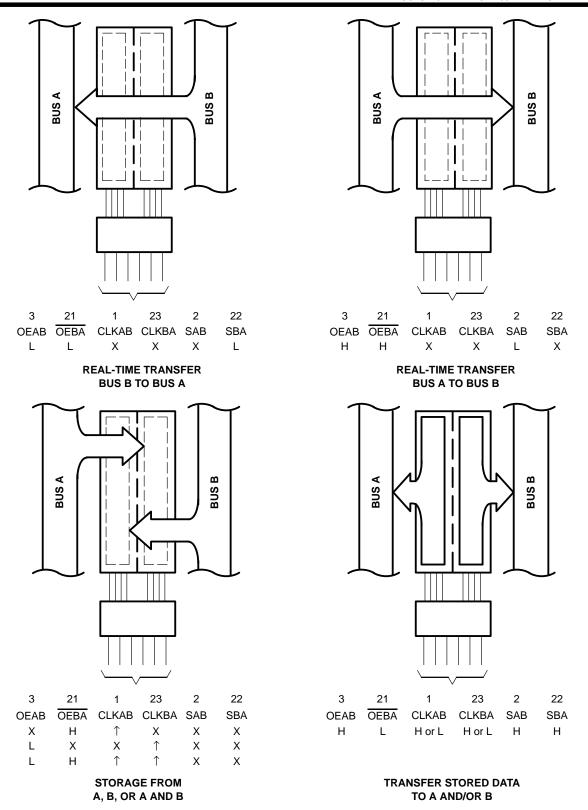
		INPU <sup>-</sup>	rs			DATA	∆ I/O†	OPERATION OR FUNCTION
OEAB	OEBA	CLKAB	CLKBA	SAB	SBA	A1-A8	B1-B8	OPERATION OR FUNCTION
L	Н	H or L	H or L	Х	Х	Input	Input	Isolation
L	Н	$\uparrow$	$\uparrow$	X	X	Input	Input	Store A and B data
Х	Н	1	H or L	Х	Х	Input	Unspecified <sup>‡</sup>	Store A, hold B
Н	Н	$\uparrow$	$\uparrow$	X‡	X	Input	Output	Store A in both registers
L	Х	H or L	1	Х	Х	Unspecified <sup>‡</sup>	Input	Hold A, store B
L	L	<b>↑</b>	1	Χ	χ‡	Output	Input	Store B in both registers
L	L	Х	Х	Х	L	Output	Input	Real-time B data to A bus
L	L	Χ	H or L	Х	Н	Output	Input	Stored B data to A bus
Н	Н	Χ	Х	L	Х	Input	Output	Real-time A data to B bus
Н	Н	H or L	Χ	Н	X	Input	Output	Stored A data to B bus
Н	L	H or L	H or L	Н	Н	Output	Output	Stored A data to B bus and stored B data to A bus

<sup>†</sup> The data-output functions can be enabled or disabled by a variety of level combinations at OEAB or OEBA. Data-input functions always are enabled; i.e., data at the bus terminals is stored on every low-to-high transition on the clock inputs.



<sup>‡</sup> Select control = L: clocks can occur simultaneously.

Select control = H: clocks must be staggered to load both registers.

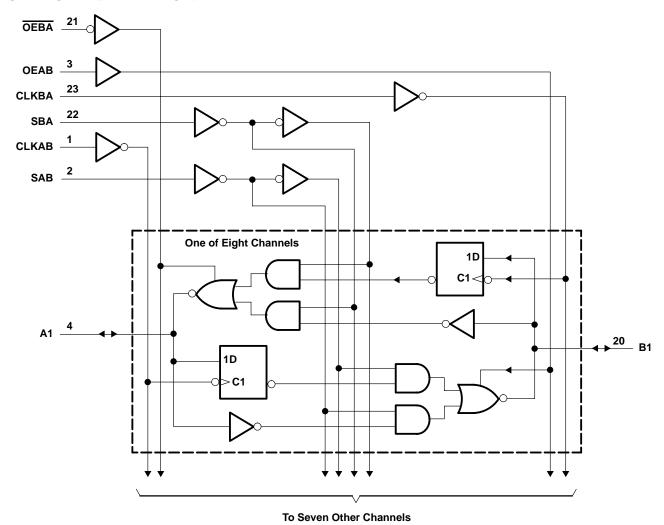


Pin numbers shown are for the DW, JT, NT, and W packages.

Figure 1. Bus-Management Functions



## logic diagram (positive logic)



Pin numbers shown are for the DW, JT, NT, and W packages.

## absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V <sub>CC</sub>	–0.5 V to 7 V
Input clamp current, I <sub>IK</sub> (V <sub>I</sub> < 0 or V <sub>I</sub> > V <sub>CC</sub> ) (see Note 1)	±20 mA
Output clamp current, $I_{OK}$ ( $V_O < 0$ or $V_O > V_{CC}$ ) (see Note 1)	±20 mA
Continuous output current, $I_O$ ( $V_O = 0$ to $V_{CC}$ )	±35 mA
Continuous current through V <sub>CC</sub> or GND	±70 mA
Package thermal impedance, θ <sub>JA</sub> (see Note 2): DW package	46°C/W
(see Note 3): NT package	
Storage temperature range, T <sub>stg</sub>	

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.
  - 2. The package thermal impedance is calculated in accordance with JESD 51-7.
  - 3. The package thermal impedance is calculated in accordance with JESD 51-3.



## recommended operating conditions (see Note 4)

			SN	54HCT6	52	SN	74HCT6	52	UNIT
			MIN	NOM	MAX	MIN	NOM	MAX	UNIT
Vcc	Supply voltage		4.5	5	5.5	4.5	5	5.5	V
VIH	High-level input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V	2		14	2			V
VIL	Low-level input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V		PA	0.8			0.8	V
VI	Input voltage		0	7	VCC	0		VCC	V
Vo	Output voltage		0	5	VCC	0		VCC	V
t <sub>t</sub>	Input transition (rise and fall) time	_	Ó	7	500			500	ns
TA	Operating free-air temperature		-55		125	-40	•	85	°C

NOTE 4: All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

# electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

DA.	RAMETER	TEST CO	NDITIONS	V	Т	A = 25°C	;	SN54H	CT652	SN74H	CT652	UNIT
PA	RAWEIER	1231 00	vcc	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNII	
Vон		$V_I = V_{IH} \text{ or } V_{IL}$		4.5 V	4.4	4.499		4.4		4.4		V
VOH		AL = AIH OLAIL	$I_{OH} = -6 \text{ mA}$	4.5 V	3.98	4.3		3.7		3.84		V
Vai		VI = VIH or VIL	$I_{OL} = 20 \mu A$	4.5 V		0.001	0.1		0.1		0.1	V
VOL		$I_{OL} = 6 \text{ mA}$		1 - VIH OF VIL   IOL = 6 mA		0.17	0.26		0.4		0.33	V
lj	Control inputs	$V_I = V_{CC}$ or 0		5.5 V		±0.1	±100		±1000		±1000	nA
loz	A or B	$V_O = V_{CC}$ or 0, Data = $V_{CC}$ or 0		5.5 V		±0.01	±0.5	200	±10		±5	μΑ
Icc		$V_I = V_{CC}$ or 0,	I <sub>O</sub> = 0	5.5 V			8	30,	160		80	μΑ
∆lcc†	-	One input at 0.5 V or 2.4 V, Other inputs at 0 or V <sub>CC</sub>		5.5 V		1.4	2.4	Yd	3		2.9	mA
Ci	Control inputs			4.5 V to 5.5 V		3	10		10		10	pF

<sup>†</sup> This is the increase in supply current for each input that is at one of the specified TTL voltage levels, rather than 0 V or VCC.

# timing requirements over recommended operating free-air temperature range (unless otherwise noted)

		v <sub>cc</sub>	T <sub>A</sub> = :	25°C	SN54H	CT652	SN74H	CT652	UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	ONII
f , ,	Clock frequency	4.5 V		25		17		20	MHz
fclock	Glock frequency	5.5 V		28		19		22	IVII IZ
	Pulse duration, CLKBA or CLKAB high or low	4.5 V	20		30	A.	25		ns
t <sub>W</sub>	Pulse duration, CERBA of CERAB high of low	5.5 V	18		27	Q'	23		115
		4.5 V	15		23		19		
t <sub>su</sub>	Setup time, A before CLKAB↑ or B before CLKBA↑	5.5 V	14		21		17		ns
<b>.</b>	Hold time, A after CLKAB↑ or B after CLKBA↑	4.5 V	5		5		5		ns
th	HOW LITTLE, A AILER CLAAD FOR B AILER CLABA	5.5 V	5		5		5	·	115

## SN54HCT652, SN74HCT652 OCTAL BUS TRANSCEIVERS AND REGISTERS WITH 3-STATE OUTPUTS

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# switching characteristics over recommended operating free-air temperature range, $C_L = 50 \text{ pF}$ (unless otherwise noted) (see Figure 2)

DADAMETED	FROM	то	V	T,	գ = 25°C	;	SN54H	CT652	SN74H	CT652	LINUT
PARAMETER	(INPUT)	(OUTPUT)	VCC	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
f			4.5 V	25	35		17		20		MHz
f <sub>max</sub>			5.5 V	28	40		19		22		IVITIZ
	CLKBA or CLKAB	A or B	4.5 V		18	36		54		45	
	CLNDA OI CLNAD	AUIB	5.5 V		16	32		49		41	
<b>4</b> .	A or B	D or A	4.5 V		14	27		41		34	
<sup>t</sup> pd	AUIB	B or A	5.5 V		12	24		37		31	ns
	004 045 <sup>†</sup>	A or B	4.5 V		20	38	6	57		48	
	SBA or SAB†		5.5 V		17	34	72	51		43	
	<del></del>	A or B	4.5 V		25	49	0	74		61	
t <sub>en</sub>	OEBA or OEAB	AUIB	5.5 V		22	44	Q	67		55	ns
4	OFAR	A a. D	4.5 V		25	49		74		61	
<sup>t</sup> dis	OEBA or OEAB	A or B	5.5 V		22	44		67		55	ns
		A m. r	4.5 V		9	12		18		15	
t <sub>t</sub>		Any	5.5 V		7	11		16		14	ns

<sup>†</sup> These parameters are measured with the internal output state of the storage register opposite that of the bus input.

# switching characteristics over recommended operating free-air temperature range, $C_L$ = 150 pF (unless otherwise noted) (see Figure 2)

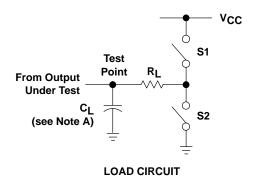
PARAMETER	FROM	то	V	T,	չ = 25°C	;	SN54H	CT652	SN74H	CT652	LINIT
PARAMETER	(INPUT)	(OUTPUT)	VCC	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
	CLKBA or CLKAB	A or B	4.5 V		24	53		80		66	
	CLNDA OF CLNAD	AUIB	5.5 V		22	47		72		60	
	A or D	D or A	4.5 V		22	44		70		55	
<sup>t</sup> pd	A or B	B or A	5.5 V		20	39		60		50	ns
	004 045 <sup>±</sup>	A D	4.5 V		26	55		83		69	
	SBA or SAB†	A or B	5.5 V		24	49	2	74		62	
	<del></del>	A D	4.5 V		33	66	0	100		82	
<sup>t</sup> en	OEBA or OEAB	A or B	5.5 V		30	59	Q	90		74	ns
		A	4.5 V		17	42		63		53	
t <sub>t</sub>		Any	5.5 V		14	38		57		48	ns

<sup>†</sup> These parameters are measured with the internal output state of the storage register opposite that of the bus input.

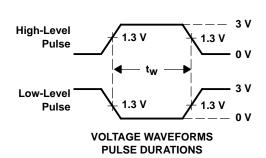
## operating characteristics, T<sub>A</sub> = 25°C

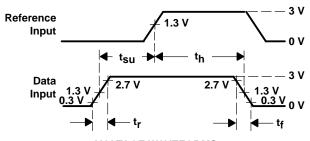
		PARAMETER	TEST CONDITIONS	TYP	UNIT
Ī	C <sub>pd</sub>	Power dissipation capacitance	No load	50	pF

### PARAMETER MEASUREMENT INFORMATION

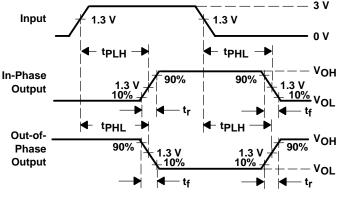


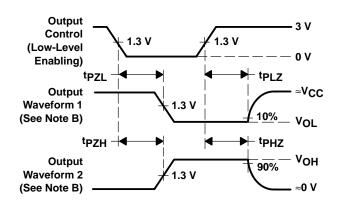
PARAI	METER	RL	CL	S1	S2
	tPZH	50 pF 1 kΩ or –		Open	Closed
t <sub>en</sub>	tPZL	1 K22	150 pF	Closed	Open
<b>.</b>	tPHZ	1 kΩ 50 pF		Open	Closed
<sup>t</sup> dis	tPLZ	1 K22	30 pr	Closed	Open
t <sub>pd</sub> or t <sub>t</sub>		-	50 pF or 150 pF	Open	Open





VOLTAGE WAVEFORMS
SETUP AND HOLD AND INPUT RISE AND FALL TIMES





VOLTAGE WAVEFORMS
PROPAGATION DELAY AND OUTPUT RISE AND FALL TIMES

VOLTAGE WAVEFORMS
ENABLE AND DISABLE TIMES FOR 3-STATE OUTPUTS

NOTES: A.  $C_L$  includes probe and test-fixture capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. Phase relationships between waveforms were chosen arbitrarily. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  1 MHz, Z<sub>O</sub> = 50  $\Omega$ , t<sub>f</sub> = 6 ns.
- D. For clock inputs,  $f_{\text{max}}$  is measured when the input duty cycle is 50%.
- E. The outputs are measured one at a time with one input transition per measurement.
- F. tpLz and tpHz are the same as tdis.
- G. tpzL and tpzH are the same as ten.
- H. tpLH and tpHL are the same as tod.

Figure 1. Load Circuit and Voltage Waveforms



11-Nov-2025 www.ti.com

#### PACKAGING INFORMATION

Orderable part number	Status (1)	Material type	Package   Pins	Package qty   Carrier	<b>RoHS</b> (3)	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
SN74HCT652DW	Obsolete	Production	SOIC (DW)   24	-	-	Call TI	Call TI	-40 to 85	HCT652
SN74HCT652DWR	Active	Production	SOIC (DW)   24	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HCT652
SN74HCT652DWR.A	Active	Production	SOIC (DW)   24	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HCT652

<sup>(1)</sup> Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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<sup>(3)</sup> RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

<sup>(4)</sup> Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

<sup>(5)</sup> MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

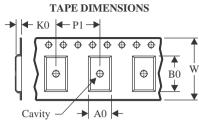
<sup>(6)</sup> Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

## **PACKAGE MATERIALS INFORMATION**

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## TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

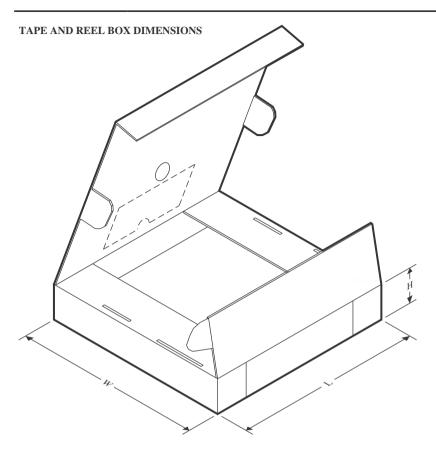


#### \*All dimensions are nominal

Device	U	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74HCT652DWR	SOIC	DW	24	2000	330.0	24.4	10.75	15.7	2.7	12.0	24.0	Q1

## **PACKAGE MATERIALS INFORMATION**

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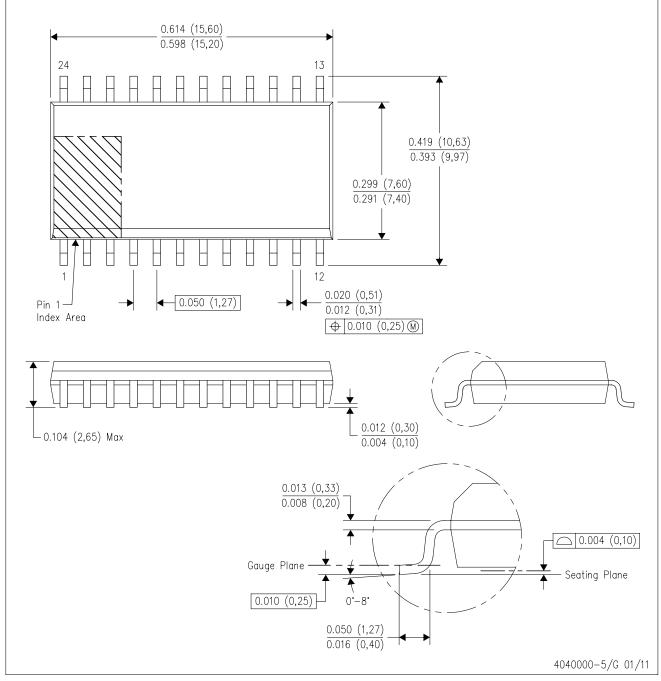


### \*All dimensions are nominal

	Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)	
I	SN74HCT652DWR	SOIC	DW	24	2000	350.0	350.0	43.0	

DW (R-PDSO-G24)

## PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters). Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-013 variation AD.



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